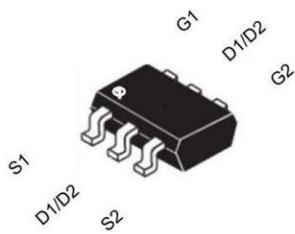


## Product Summary

- $V_{DS} = 20V, I_D = 6A$
- $R_{DS(ON)}, 19.5m\Omega$  (Typ) @  $V_{GS} = 4.5V$
- $R_{DS(ON)}, 25m\Omega$  (Typ) @  $V_{GS} = 2.5V$
- Trench Power Technology
- Low RDS(ON)
- Low Gate Charge
- Optimized for Fast-switching Applications

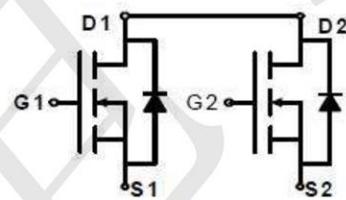
## Package and Pin Configuration



## Application

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial

## Circuit diagram



## Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 10$	V
Drain Current-Continuous <sup>Note3</sup>	$I_D$	6	A
		4.8	A
Drain Current-Pulsed <sup>Note1</sup>	$I_{DM}$	24	A
Avalanche Energy <sup>Note4</sup>	$E_{AS}$	7.4	mJ
Maximum Power Dissipation	$P_D$	1.5	W
Storage Temperature Range	$T_{STG}$	-55 to +150	°C
Operating Junction Temperature Range	$T_J$	-55 to +150	°C

## Thermal Resistance

Parameter	Symbol	Min.	Typ.	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{eJC}$	-	14.4	-	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{eJA}$	-	83	-	°C/W

**Electrical Characteristics (  $T_A = 25^\circ\text{C}$  unless otherwise noted )**

<b>OFF CHARACTERISTICS</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=250\mu\text{A}$	20	-	-	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=20\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	$\mu\text{A}$
Gate-Body Leakage	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 10\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm 100$	nA

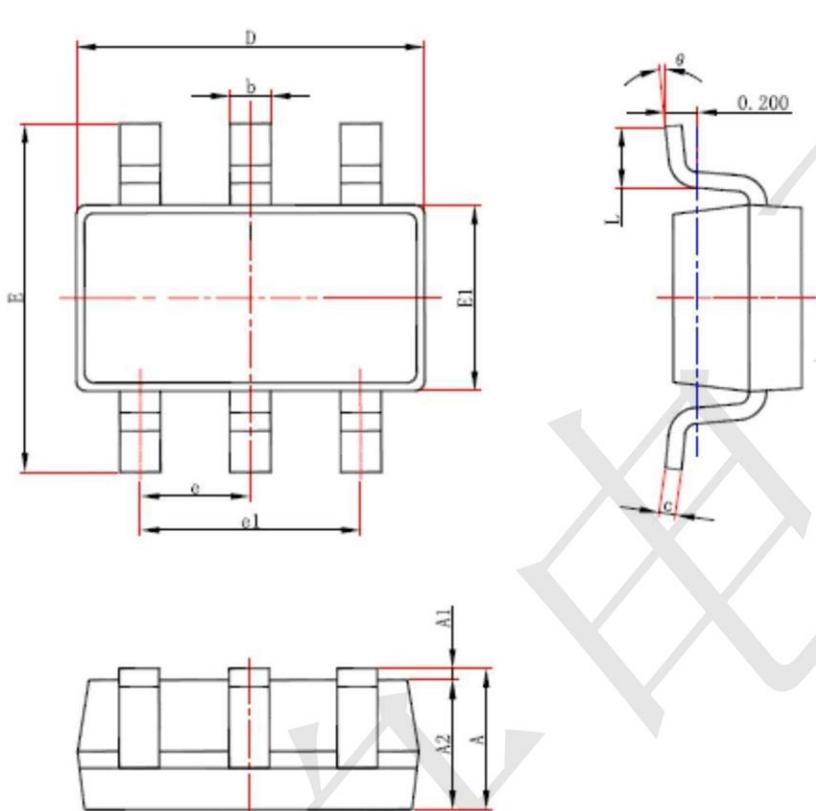
<b>ON CHARACTERISTICS</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Gate Threshold Voltage	$V_{\text{GS}(\text{TH})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{DS}}=250\mu\text{A}$	0.5	0.7	1.2	V
Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=4.5\text{V}, I_{\text{DS}}=3\text{A}$	-	19.5	25	$\text{m}\Omega$
		$V_{\text{GS}}=2.5\text{V}, I_{\text{DS}}=3\text{A}$	-	25	31.5	

<b>DYNAMIC CHARACTERISTICS</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=10\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$	-	466	-	pF
Output Capacitance	$C_{\text{oss}}$		-	65	-	
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	58	-	

<b>SWITCHING CHARACTERISTICS</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Turn-On Delay Time	$T_{\text{d(on)}}$	$V_{\text{GS}}=4.5\text{V}, V_{\text{DS}}=10\text{V}, R_{\text{GEN}}=2.5\Omega, I_{\text{D}}=6\text{A}$	-	15	-	ns
Rise Time	$t_r$		-	17	-	
Turn-Off Delay Time	$T_{\text{d(off)}}$		-	42	-	
Fall Time	$t_f$		-	10	-	
Total Gate Charge at 10V	$Q_g$	$V_{\text{DS}}=10\text{V}, I_{\text{DS}}=6\text{A}, V_{\text{GS}}=10\text{V}$	-	5.7	-	nC
Gate to Source Gate Charge	$Q_{\text{gs}}$		-	0.8	-	
Gate to Drain "Miller" Charge	$Q_{\text{gd}}$		-	1.4	-	

<b>DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Drain-Source Diode Forward Voltage	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=6\text{A}$	-	-	1.2	V

SOT23-6 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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